



◆Thyristor Maximum Ratings

Symbol	Item	Conditions	Values	Units
I_{TAV}	Average On-State Current	$T_c=93^{\circ}\text{C}$, Single Phase half wave 180° conduction	200	A
I_{TSM}	Surge On-State Current	$T_{VJ}=45^{\circ}\text{C}$ $t=10\text{ms}$ (50Hz), sine $V_R=0$	4500	A
i^2t	Circuit Fusing Consideration		101250	A^2s
Visol	Isolation Breakdown Voltage(R.M.S)	a.c.50HZ;r.m.s.;1 min	3000	V
T_{vj}	Operating Junction Temperature		-40 to +125	$^{\circ}\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^{\circ}\text{C}$
M_t	Mounting Torque	To terminals(M4)	$2\pm 15\%$	Nm
M_t		To terminals(M6)	$5\pm 15\%$	
M_s		To heatsink(M6)	$5\pm 15\%$	Nm
di/dt	Critical Rate of Rise of On-State Current	$T_{VJ}=T_{VJM}$, $V_D=1/2V_{DRM}$, $I_G=100\text{mA}$ $d_i/d_t=0.1\text{A}/\mu\text{s}$	200	$\text{A}/\mu\text{s}$
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	$T_J=T_{VJM}$, $V_D=2/3V_{DRM}$, linear voltage rise	500	$\text{V}/\mu\text{s}$

Electrical and Thermal Characteristics

Symbol	Item	Conditions	Values			Units
			Min.	Typ.	Max.	
V_{TM}	Peak On-State Voltage, max.	$T=25^{\circ}\text{C}$ $I_T=200\text{A}$			1.40	V
I_{RRM}/I_{DRM}	Repetitive Peak Reverse Current, max. / Repetitive Peak Off-State Current, max.	$T_{VJ}=T_{VJM}$, $V_R=V_{RRM}$, $V_D=V_{DRM}$			100	mA
V_{GT}	Gate Trigger Voltage, max.	$T_{VJ}=25^{\circ}\text{C}$, $V_D=6\text{V}$			3	V
I_{GT}	Gate Trigger Current, max.	$T_{VJ}=25^{\circ}\text{C}$, $V_D=6\text{V}$			150	mA
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to Case			0.14	$^{\circ}\text{C}/\text{W}$
$R_{th(c-s)}$	Thermal Impedance, max.	Case to Heat sink			0.06	$^{\circ}\text{C}/\text{W}$



Performance Curves

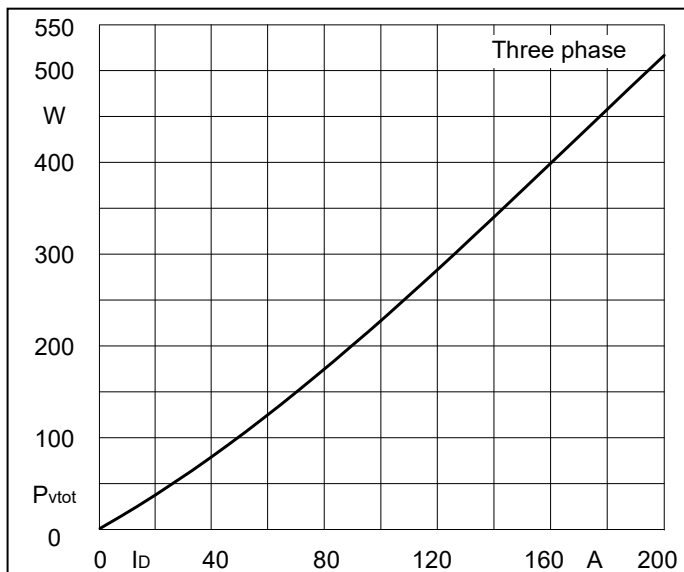


Fig1. Power dissipation

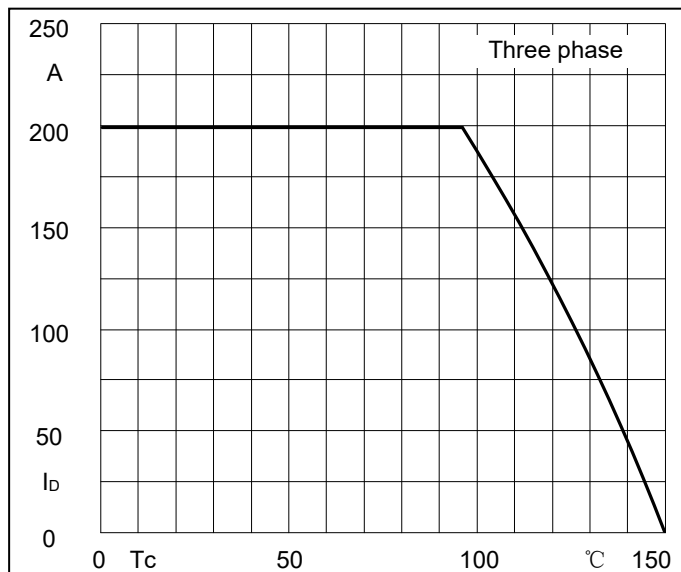


Fig2. Forward Current Derating Curve

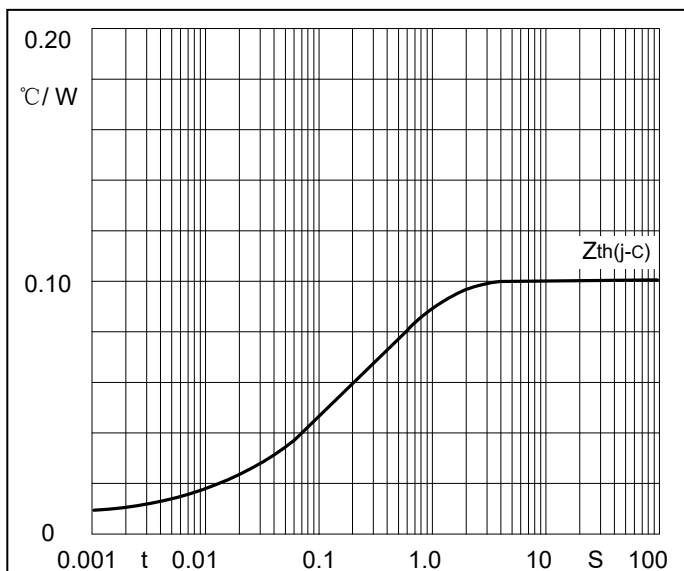


Fig3. Transient thermal impedance

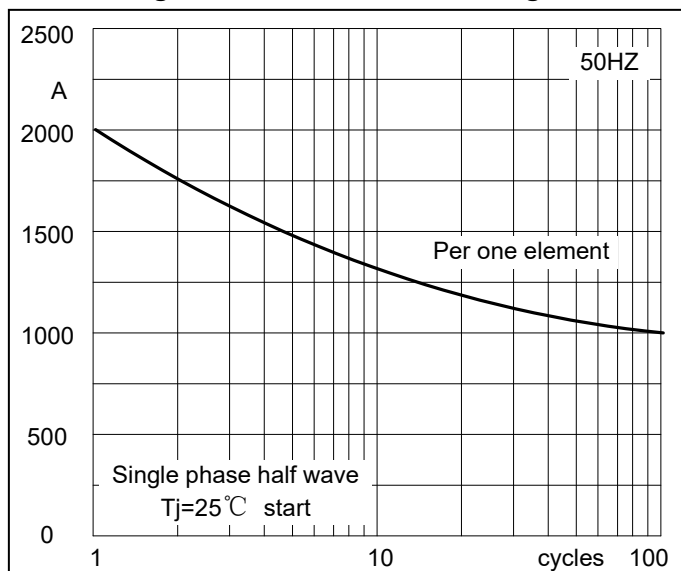


Fig4. Max Non-Repetitive Forward Surge Current

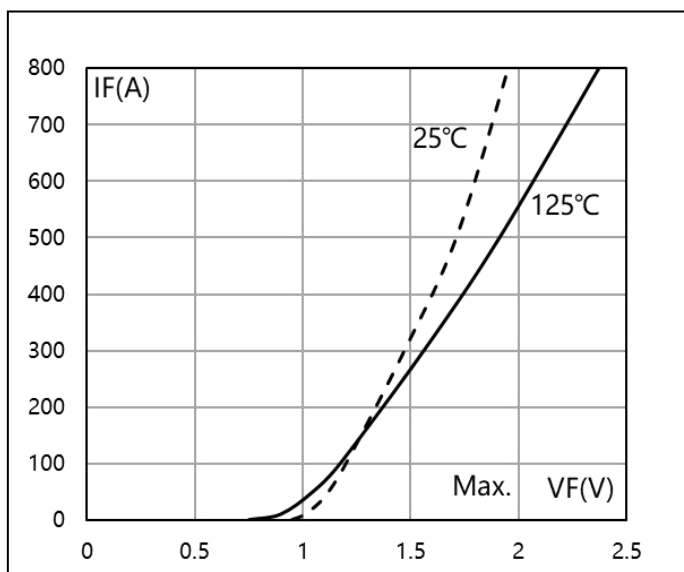


Fig5. Forward Characteristics

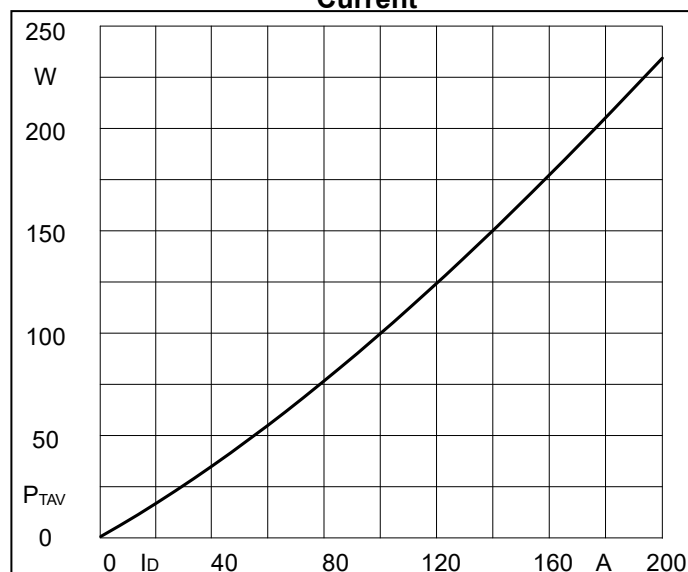


Fig6. SCR Power dissipation

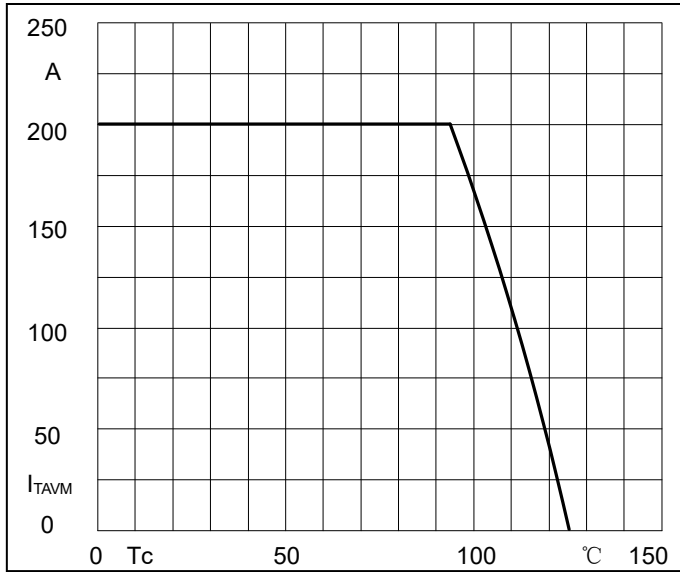


Fig7. SCR Forward Current Derating Curve

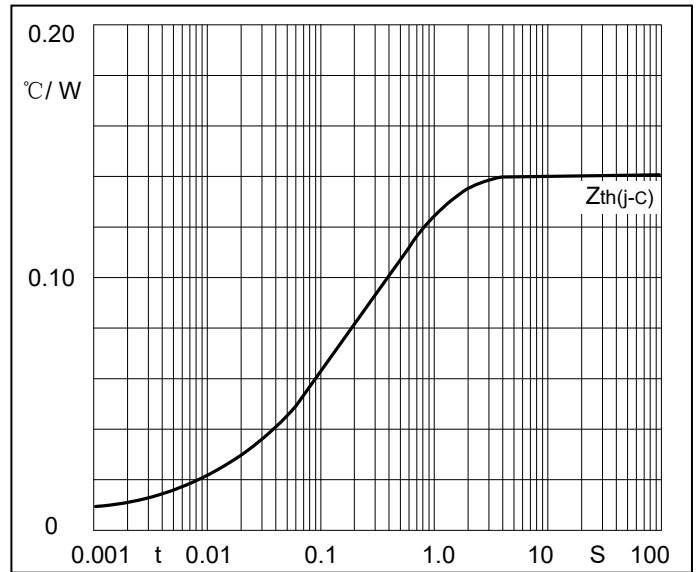


Fig8. SCR Transient thermal impedance

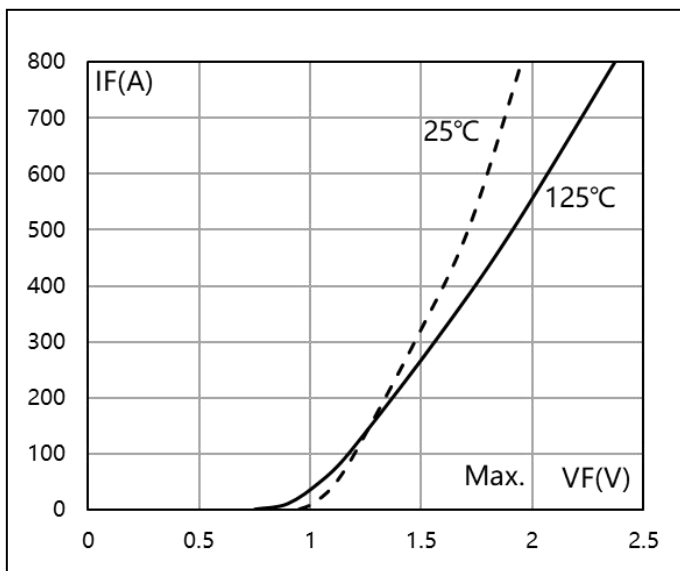


Fig9. SCR Forward Characteristics

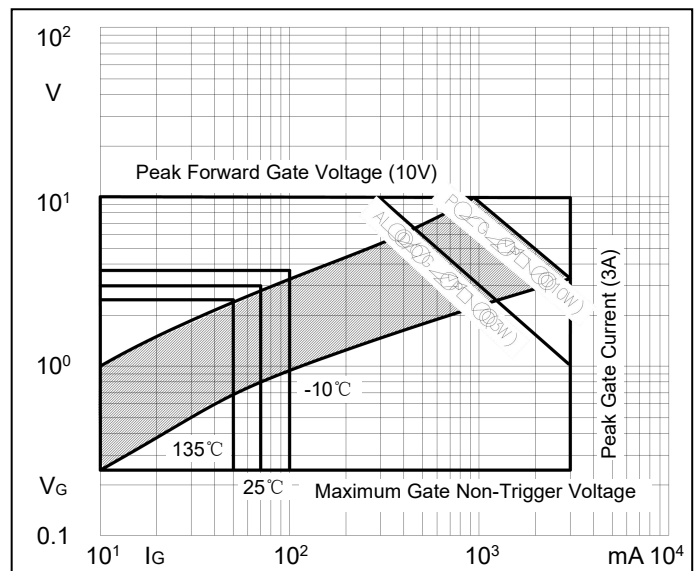
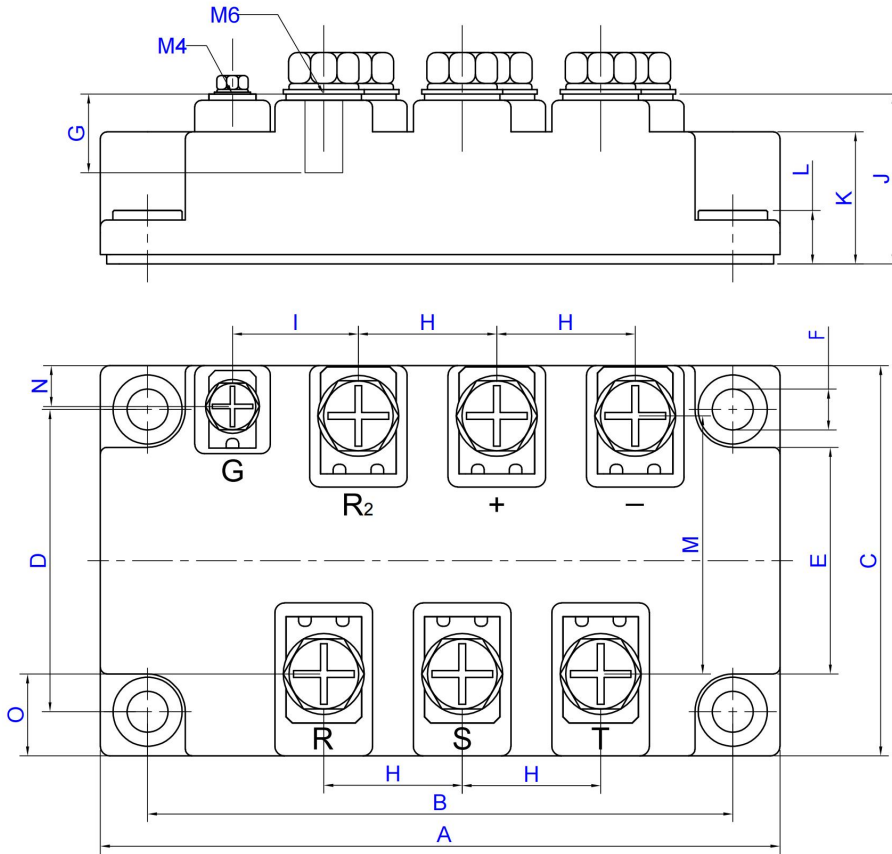


Fig10. Gate trigger Characteristics

Package Outline Information

CASE: L2



DIM	Min (mm)	Max (mm)	Note
A	108	109	
B	92.5	93.5	
C	61.5	62.5	
D	47.5	48.5	
E	35.5	36.5	
F	6.2	6.8	Ø
G	12	13	
H	21.5	22.5	
I	19.5	20.5	
J	26.5	27.5	
K	20.5	21.5	
L	8	9	
M	40.5	41.5	
N	6	7	
O	12.5	13.5	

Packing Standard

Item	Length: A (mm)	Width: B (mm)	Height: C (mm)	Quantity (PCS)
Inner Box	276	258	48	4
Outer Carton	545	295	240	40



Disclaimer

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